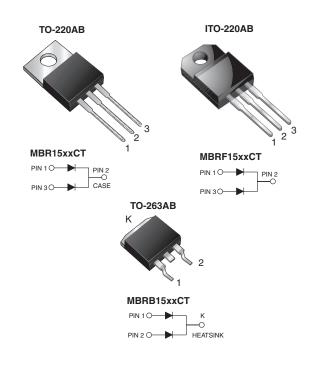


Vishay General Semiconductor

Dual Common-Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	7.5 A x 2				
V _{RRM}	35 V to 60 V				
I _{FSM}	150 A				
V _F	0.57 V, 0.65 V				
T _J max.	150 °C				

FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT	
Maximum repetitive peak reverse voltage		35	45	50	60	V	
Working peak reverse voltage		35	45	50	60	V	
Maximum DC blocking voltage		35	45	50	60	V	
$\begin{array}{ll} \mbox{Maximum average forward rectified} & \mbox{total device} \\ \mbox{current at } T_{C} = 105 \ ^{\circ}\mbox{C} & \mbox{per diode} \end{array}$	I _{F(AV)}	15 7.5			А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150				А	
Peak repetitive reverse surge current per diode at t_p = 2.0 $\mu s,1$ kHz	I _{RRM}	1.0 0.5		.5	A		
Voltage rate of change (rated V _R)	dV/dt	10 000				V/µs	
Operating junction temperature range	Т _Ј	- 65 to + 150			°C		

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MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL MBR1535CT MBR1545CT MBR1550CT MBR1560CT						
Storage temperature range	T _{STG}	- 65 to + 175			°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			v		

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾		$T_{C} = 25 °C$ $T_{C} = 125 °C$ $T_{C} = 25 °C$ $T_{C} = 125 °C$	V _F	- 0.57 0.84 0.72		0. 0.	-	V
Maximum instantaneous reverse current at rated DC blocking voltage per diode ⁽¹⁾		T _C = 25 °C T _C = 125 °C	I _R	0.1 15		1. 5	.0 0	mA

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER SYMBOL MBR MBRF MBRB						
Maximum thermal resistance per diode	$R_{ heta JA} \ R_{ heta JC}$	60 3.0	- 5.0	60 3.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR1545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/81	1.35	81	800/reel	Tape reel		
TO-220AB	MBR1545CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/81 (1)	1.35	81	800/reel	Tape reel		

Note:

(1) Automotive grade AEC Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

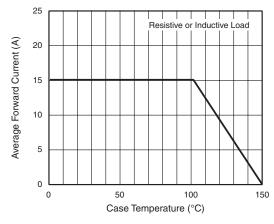


Figure 1. Forward Current Derating Curve

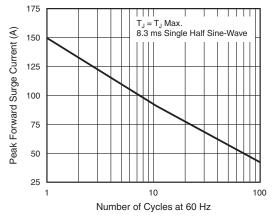


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

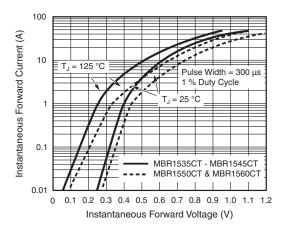


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

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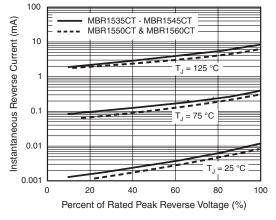


Figure 4. Typical Reverse Characteristics Per Diode

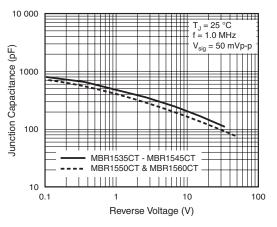


Figure 5. Typical Junction Capacitance Per Diode

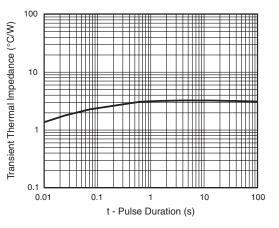


Figure 6. Typical Transient Thermal Impedance Per Diode

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0.190 (4.83)

0.170 (4.32)

0.110 (2.79)

0.100 (2.54)

0.135 (3.43) DIA.

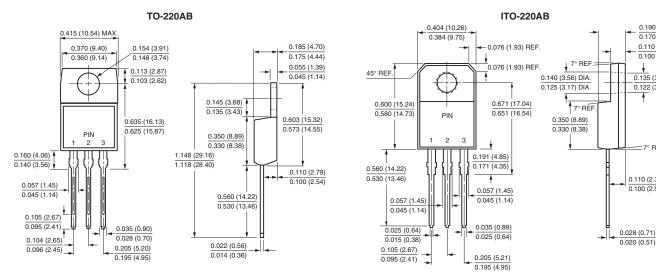
0.122 (3.08) DIA ł

7° REF

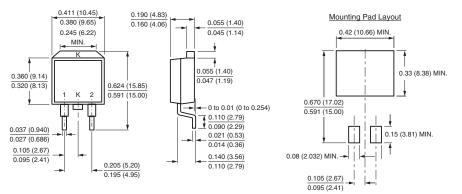
0.110 (2.79)

0.100 (2.54)

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB





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